

### SURFACE MOUNT SILICON COMPLEMENTARY POWER DARLINGTON TRANSISTORS





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## DESCRIPTION:

The CENTRAL SEMICONDUCTOR CJD112 and CJD117 are complementary silicon power Darlington transistors manufactured in a surface mount package designed for low speed switching and amplifier applications.

### MARKING: FULL PART NUMBER

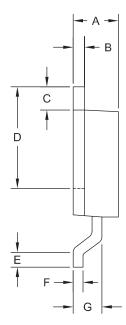
MAXIMUM RATINGS: (T<sub>C</sub>=25°C unless otherwise noted) SYMBOL UNITS Collector-Base Voltage VCBO 100 V Collector-Emitter Voltage VCEO 100 V Emitter-Base Voltage VEBO 5.0 V Continuous Collector Current  $I_{C}$ 2.0 А Peak Collector Current 4.0 А ICM **Continuous Base Current** 50 ΙB mA **Power Dissipation**  $\mathsf{P}_\mathsf{D}$ 20 W  $\mathsf{P}_\mathsf{D}$ Power Dissipation (T<sub>A</sub>=25°C) 1.75 W Operating and Storage Junction Temperature -65 to +150 °C TJ, Tsta Thermal Resistance ΘJC 6.25 °C/W Thermal Resistance °C/W 71.4  $\Theta_{\mathsf{JA}}$ ELECTRICAL CHARACTERISTICS: (T<sub>C</sub>=25°C unless otherwise noted) SYMBOL **TEST CONDITIONS** MIN MAX UNITS V<sub>CF</sub>=50V 20 μΑ ICEO VCE=80V, VBE(off)=1.5V 10 μA **ICEV** V<sub>CE</sub>=80V, V<sub>BE(off)</sub>=1.5V, T<sub>C</sub>=125°C 500 μA **ICEV** V<sub>CB</sub>=80V 10 μA Ісво V<sub>CB</sub>=100V 20 μA Ісво V<sub>FB</sub>=5.0V 2.0 mΑ I<sub>EBO</sub> I<sub>C</sub>=30mA 100 V BVCEO I<sub>C</sub>=2.0A, I<sub>B</sub>=8.0mA 2.0 V VCE(SAT) IC=4.0A, IB=40mA 3.0 V VCE(SAT) IC=4.0A, IB=40mA 4.0 V VBE(SAT) V<sub>CF</sub>=3.0V, I<sub>C</sub>=2.0A V 2.8 V<sub>BE(ON)</sub> V<sub>CE</sub>=3.0V, I<sub>C</sub>=0.5A 500 hFE V<sub>CE</sub>=3.0V, I<sub>C</sub>=2.0A 12000  $^{h}\mathsf{FE}$ 1000 V<sub>CE</sub>=3.0V, I<sub>C</sub>=4.0A 200 hFE V<sub>CE</sub>=10V, I<sub>C</sub>=750mA, f=1.0MHz fT 25 MHz V<sub>CB</sub>=10V, I<sub>E</sub>=0, f=0.1MHz (CJD112) 100 Cob pF 200 Cob V<sub>CB</sub>=10V, I<sub>E</sub>=0, f=0.1MHz (CJD117) pF

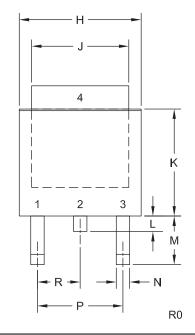
R3 (21-January 2013)



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# DPAK CASE - MECHANICAL OUTLINE





# LEAD CODE:

- 1) Base
- 2) Collector
- 3) Emitter
- 4) Collector

MARKING: FULL PART NUMBER

DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
A	0.083	0.108	2.10	2.75
В	0.016	0.032	0.40	0.81
С	0.035	0.063	0.89	1.60
D	0.203	0.228	5.15	5.79
E	0.020	-	0.51	-
F	0.018	0.024	0.45	0.60
G	0.051	0.071	1.30	1.80
Н	0.248	0.268	6.30	6.81
J	0.197	0.217	5.00	5.50
K	0.209	0.245	5.30	6.22
L	0.025	0.040	0.64	1.02
М	0.090	0.115	2.30	2.91
N	0.012	0.045	0.30	1.14
Р	0.180		4.60	
R	0.090		2.30	
DPAK (REV: R0)				

R3 (21-January 2013)

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- Inventory bonding
- Consolidated shipping options

- Custom bar coding for shipments
- Custom product packing

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- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

## CONTACT US

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